Low-power configurable gate with voltage-level translatorRev. 5 — 15 August 2012Product data sheet

1. General description

The 74AUP1T58 provides low-power, low-voltage configurable logic gate functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions AND, OR, NAND, NOR, XOR, inverter and buffer. All inputs can be connected to V_{CC} or GND.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 2.3 V to 3.6 V.

The 74AUP1T58 is designed for logic-level translation applications with input switching levels that accept 1.8 V low-voltage CMOS signals, while operating from either a single 2.5 V or 3.3 V supply voltage.

The wide supply voltage range ensures normal operation as battery voltage drops from 3.6 V to 2.3 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

Schmitt trigger inputs make the circuit tolerant to slower input rise and fall times across the entire V_{CC} range.

2. Features and benefits

- Wide supply voltage range from 2.3 V to 3.6 V
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 1.5 \ \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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3. Ordering information

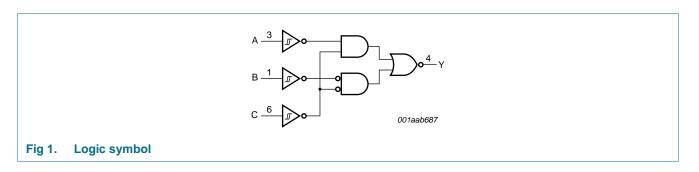
Table 1. Ordering	g information			
Type number	Package			
	Temperature range	Name	Description	Version
74AUP1T58GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363
74AUP1T58GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886
74AUP1T58GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm	SOT891
74AUP1T58GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115
74AUP1T58GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202

4. Marking

Table 2. Marking	
Type number	Marking code ^[1]
74AUP1T58GW	a8
74AUP1T58GM	a8
74AUP1T58GF	a8
74AUP1T58GN	a8
74AUP1T58GS	a8

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

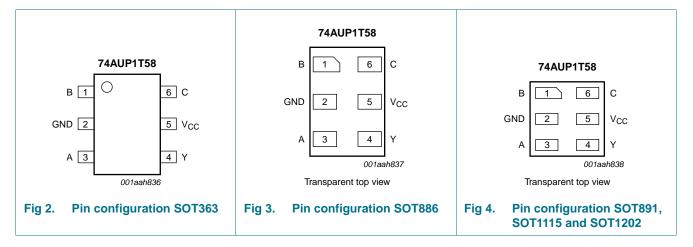
5. Functional diagram



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6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
В	1	data input
GND	2	ground (0 V)
A	3	data input
Y	4	data output
V _{CC}	5	supply voltage
С	6	data input

7. Functional description

Table 4.	Function table ^[1]		
Input		Output	
С	В	Α	Y
L	L	L	L
L	L	Н	Н
L	Н	L	L
L	Н	Н	Н
Н	L	L	Н
Н	L	Н	Н
Н	Н	L	L
Н	Н	Н	L

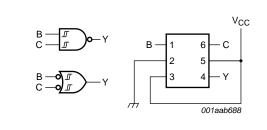
[1] H = HIGH voltage level; L = LOW voltage level.

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7.1 Logic configurations

Table 5.Function selection table

Logic function	Figure
2-input NAND	see Figure 5
2-input NAND with both inputs inverted	see Figure 8
2-input AND with inverted input	see <u>Figure 6</u> and <u>7</u>
2-input NOR with inverted input	see <u>Figure 6</u> and <u>7</u>
2-input OR	see Figure 8
2-input OR with both inputs inverted	see Figure 5
2-input XOR	see Figure 9
Buffer	see Figure 10
Inverter	see Figure 11



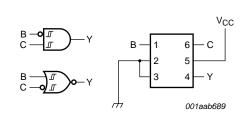


Fig 5. 2-input NAND gate or 2-input OR gate with both inputs inverted

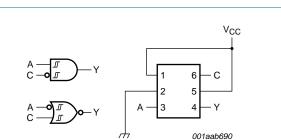


Fig 7. 2-input AND gate with input C inverted or 2-input NOR gate with inverted A input



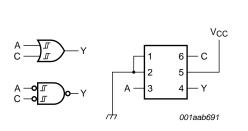
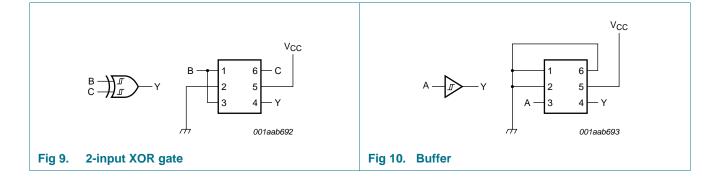
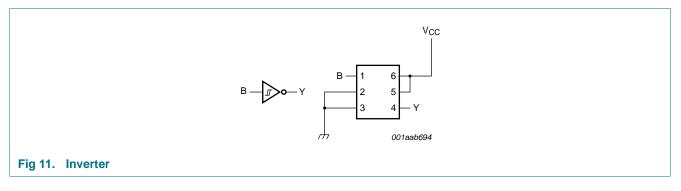


Fig 8. 2-input OR gate or 2-input NAND gate with both inputs inverted



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Limiting values 8.

Table 6. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode	<u>[1]</u> –0.5	+4.6	V
I _O	output current	$V_{O} = 0 V \text{ to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	٥C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +125 \ ^{\circ}C$	[2] _	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SC-88 package: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K. [2] For XSON6 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

Recommended operating conditions 9.

Table 7.	Recommended operating cond	ditions			
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		2.3	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; $V_{CC} = 0 V$	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

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10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	25 °C					
V _{T+}	positive-going threshold	V_{CC} = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.75	-	1.16	V
V _{T-}	negative-going threshold	V_{CC} = 2.3 V to 2.7 V	0.35	-	0.60	V
	voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.50	-	0.85	V
V _H	hysteresis voltage	$(V_H=V_{T+}-V_{T-})$				
		V_{CC} = 2.3 V to 2.7 V	0.23	-	0.60	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.25	-	0.56	V
V _{ОН}	HIGH-level output voltage	$V_I = V_{T+} \text{ or } V_{T-}$				
		I_{O} = –20 $\mu A; V_{CC}$ = 2.3 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	2.05	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_{O} = -2.7$ mA; $V_{CC} = 3.0$ V	2.72	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+} \text{ or } V_{T-}$				
		$I_0 = 20 \ \mu$ A; $V_{CC} = 2.3 \ V$ to 3.6 V	-	-	0.10	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.31	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.44	V
I _I	input leakage current	V_1 = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.1	μA
ΔI_{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I _{CC}	supply current	$V_{I} = \text{GND or } V_{\text{CC}}; I_{\text{O}} = 0 \text{ A};$ $V_{\text{CC}} = 2.3 \text{ V to } 3.6 \text{ V}$	-	-	1.2	μA
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V_{I} = GND or V_{CC}	-	0.8	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.7	-	pF
T _{amb} = -	-40 °C to +85 °C					
V _{T+}	positive-going threshold	V_{CC} = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	0.75	-	1.19	V
V _{T-}	negative-going threshold	V_{CC} = 2.3 V to 2.7 V	0.35	-	0.60	V
	voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.50	-	0.85	V
V _H	hysteresis voltage	$(V_H = V_T+ - V_T-)$				
		V_{CC} = 2.3 V to 2.7 V	0.10	-	0.60	V

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Table 8. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{он}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = –20 $\mu A;$ V_{CC} = 2.3 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = 20 μ A; V_{CC} = 2.3 V to 3.6 V	-	-	0.1	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.33	V
		$I_0 = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.45	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.33	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.45	V
I	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.5	μA
OFF	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
∆l _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.5	μA
СС	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 2.3 \text{ V to } 3.6 \text{ V}$	-	-	1.5	μA
∆l _{CC}	additional supply current	V_{CC} = 2.3 V to 2.7 V; I_{O} = 0 A	<u>[1]</u> -	-	4	μA
		V_{CC} = 3.0 V to 3.6 V; I _O = 0 A	[2] _	-	12	μA
Γ _{amb} = −	40 °C to +125 °C					
V _{T+}	positive-going threshold	V_{CC} = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.75	-	1.19	V
V _{T-}	negative-going threshold	V_{CC} = 2.3 V to 2.7 V	0.33	-	0.64	V
	voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.46	-	0.85	V
V _H	hysteresis voltage	$(V_H = V_T+ - V_T-)$				
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$	0.10	-	0.60	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.15	-	0.56	V
√ _{ОН}	$ \begin{aligned} & _{0} = -20 \ \mu^{2}, V_{CC} = 2.3 \ V \ 0.3 \ V \ V_{CC} - 0.1 \ & & - \\ & _{0} = -2.3 \ m^{2}, V_{CC} = 2.3 \ V & 1.97 \ & & - \\ & _{0} = -3.1 \ m^{2}, V_{CC} = 2.3 \ V & 1.85 \ & & - \\ & _{0} = -3.1 \ m^{2}, V_{CC} = 3.0 \ V & 2.57 \ & & - \\ & _{0} = -4.0 \ m^{2}, V_{CC} = 3.0 \ V & 2.55 \ & & - \\ & _{0} = -20 \ \mu^{2}, V_{CC} = 2.3 \ V \ 0.50 \ V & - \ & & - \\ & _{0} = -20 \ \mu^{2}, V_{CC} = 2.3 \ V \ 0.50 \ V & - \ & & - \\ & _{0} = -20 \ m^{2}, V_{CC} = 2.3 \ V \ & - \ & - \ & 0.1 \ \\ & _{0} = 2.3 \ m^{2}, V_{CC} = 2.3 \ V \ & - \ & - \ & 0.45 \ \\ & _{0} = 2.7 \ m^{2}, V_{CC} = 3.0 \ V \ & - \ & - \ & 0.45 \ \\ & _{0} = 2.7 \ m^{2}, V_{CC} = 3.0 \ V \ & - \ & - \ & 0.45 \ \\ & _{0} = 2.7 \ m^{2}, V_{CC} = 3.0 \ V \ & - \ & - \ & 0.45 \ \\ & _{0} = 2.7 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & 0.45 \ \\ & _{0} = 2.7 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & 0.45 \ \\ & _{0} = 2.0 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & 0.45 \ \\ & _{0} = 2.7 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & 0.45 \ \\ & _{0} = 2.7 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & 0.45 \ \\ & _{0} = 2.0 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & 0.45 \ \\ & _{0} = 2.0 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & 0.45 \ \\ & _{0} = 2.0 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & - \ & 0.55 \ \\ & _{0} = 1.0 \ V_{CC} = 0 \ V \ & 0.2 \ V \ \\ & _{0} = 0 \ A \ & _{0} = - \ & - \ & 1.5 \ \\ & _{0} = -0 \ A \ & V_{CC} = 2.3 \ V \ 0.3 \ A \ & V_{CC} = - \ & 1.5 \ \\ & _{0} = -2.3 \ V \ 0.3 \ A \ & V_{CC} = 0 \ A \ & _{1} - \ & - \ & 1.5 \ \\ & _{0} = - \ & - \ & 1.5 \ \\ & _{0} = -2.3 \ V \ & 0.3 \ V \ & 0.75 \ & - \ & 1.10 \ \\ & v_{CC} = 3.0 \ V \ 0.3 \ A \ & 0.75 \ & - \ & 1.10 \ \\ & v_{CC} = 3.0 \ V \ 0.3 \ & 0 \ & 0.75 \ & - \ & 1.10 \ \\ & v_{CC} = 3.0 \ V \ 0.3 \ & 0 \ & 0.15 \ & - \ & 0.60 \ \\ & v_{CC} = 3.0 \ V \ 0.3 \ & 0 \ & 0.15 \ & - \ & 0.60 \ \\ & v_{CC} = -2.0 \ & 0.10 \ & - \ & 0.60 \ \\ & v_{CC} = -2.0 \ & 0.10 \ & - \ & 0.60 \ \\ & v_{CC} = -2.0 \ & 0.50 \ & 0.50 \ \\ & v_{CC} = -2.0 \ & 0.50 \ & 0.50 \ \\ & v_{CC} = -2.0 \ & 0.50 \ & 0.50 \$					
		I_{O} = -20 μ A; V _{CC} = 2.3 V to 3.6 V	V _{CC} - 0.11	-	0.33 0.45 0.33 0.45 ±0.5 ±0.5 ±0.5 1.5 4 12 1.10 1.19 0.64 0.85 0.60 0.56 - - - - - - 0.11 0.36 0.50 0.36 0.50	V
		$I_0 = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.77	-	-	V
			1.67	-	-	V
		$I_0 = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.40	-	-	V
			2.30	-	-	V
√ _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
02			-	-	0.11	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.36	V
			-	-		V
			-	-		V
			-	-		V
	input leakage current	0 00		-		μA
	Transa and a contraint		•			•
4AUP1T58	ata sheet	All information provided in this document is subject to legal discla Rev. 5 — 15 August 2012	aimers.		© Nexperia B.V. 2017. A	Il rights reserv 7 of 2

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At recom	mended operating conditions	s; voltages are referenced to GND (grou	und = 0 V).			
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{OFF}	power-off leakage current	$V_{I} \text{ or } V_{O}$ = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μA
ΔI_{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.75	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 2.3 \text{ V to } 3.6 \text{ V}$	-	-	3.5	μA
ΔI_{CC}	additional supply current	V_{CC} = 2.3 V to 2.7 V; I_{O} = 0 A	<u>[1]</u> -	-	7	μA
		V_{CC} = 3.0 V to 3.6 V; I_O = 0 A	[2] _	-	22	μA

Table 8. Static characteristics ... continued

[1] One input at 0.3 V or 1.1 V, other input at $V_{CC} \mbox{ or GND}.$

[2] One input at 0.45 V or 1.2 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 13.

Symbol	Parameter	Conditions		25 °C			–40 °C to +125 °C			
			Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)		
$V_{CC} = 2.2$	3 V to 2.7 V; V _I = 1.6	5 V to 1.95 V								
t _{pd}	propagation delay	A, B, C to Y; see Figure 12	[2]							
		C _L = 5 pF	2.1	3.6	5.6	0.5	6.8	7.5	ns	
		C _L = 10 pF	2.6	4.1	6.2	1.0	7.9	8.7	ns	
		C _L = 15 pF	3.0	4.6	6.8	1.0	8.7	9.6	ns	
		C _L = 30 pF	4.0	5.8	8.1	1.5	10.8	11.9	ns	
$V_{CC} = 2.5$	3 V to 2.7 V; V _I = 2.3	3 V to 2.7 V								
t _{pd}	propagation delay	A, B, C to Y; see Figure 12	[2]							
		C _L = 5 pF	1.7	3.4	5.5	0.5	6.0	6.6	ns	
		C _L = 10 pF	2.2	4.0	6.2	1.0	7.1	7.9	ns	
		C _L = 15 pF	2.6	4.5	6.8	1.0	7.9	8.7	ns	
		C _L = 30 pF	3.5	5.6	8.1	1.5	10.0	11.0	ns	
$V_{\rm CC} = 2.2$	3 V to 2.7 V; V _I = 3.0) V to 3.6 V								
t _{pd}	propagation delay	A, B, C to Y; see Figure 12	[2]							
		C _L = 5 pF	1.4	3.2	5.1	0.5	5.5	6.1	ns	
		C _L = 10 pF	1.9	3.7	5.8	1.0	6.5	7.2	ns	
		C _L = 15 pF	2.2	4.2	6.3	1.0	7.4	8.2	ns	
		C _L = 30 pF	3.2	5.4	7.7	1.5	9.5	10.5	ns	
$V_{CC} = 3.$	0 V to 3.6 V; V _I = 1.6	65 V to 1.95 V								
t _{pd}	propagation delay	A, B, C to Y; see Figure 12	[2]							
		C _L = 5 pF	2.0	2.9	4.0	0.5	8.0	8.8	ns	
		C _L = 10 pF	2.4	3.5	4.7	1.0	8.5	9.4	ns	
		C _L = 15 pF	2.8	3.9	5.3	1.0	9.1	10.1	ns	
		C _L = 30 pF	3.6	5.1	6.7	1.5	9.8	10.8	ns	

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Symbol	Parameter	Conditions		25 °C		-4	0 °C to +1	25 °C	Unit
				Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Max (125 °C)	
V _{CC} = 3.	0 V to 3.6 V; V _I = 2.3	3 V to 2.7 V							
t _{pd}	propagation delay	A, B, C to Y; see Figure 12							
		C _L = 5 pF	1.6	2.8	4.4	0.5	5.3	5.9	ns
		C _L = 10 pF	2.1	3.4	5.1	1.0	6.1	6.8	ns
		C _L = 15 pF	2.4	3.9	5.6	1.0	6.8	7.5	ns
		C _L = 30 pF	3.4	5.0	7.0	1.5	8.5	9.4	ns
V _{CC} = 3.	0 V to 3.6 V; V _I = 3.0) V to 3.6 V							
t _{pd}	propagation delay	A, B, C to Y; see Figure 12							
		C _L = 5 pF	1.3	2.8	4.4	0.5	4.7	5.2	ns
		C _L = 10 pF	1.7	3.3	5.1	1.0	5.7	6.3	ns
		C _L = 15 pF	2.1	3.8	5.7	1.0	6.2	6.9	ns
		C _L = 30 pF	3.1	4.9	7.0	1.5	7.8	8.6	ns
T _{amb} = 2	5 °C								
C _{PD}	power dissipation	$f_i = 1 \text{ MHz}; V_i = \text{GND to } V_{\text{CC}}$ [3]							
	capacitance	V_{CC} = 2.3 V to 2.7 V	-	3.6	-	-	-	-	pF
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	4.3	-	-	-	-	pF

Table 9. Dynamic characteristics ... continued

[1] All typical values are measured at nominal $V_{\mbox{CC}}.$

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}{}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}{}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

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12. Waveforms

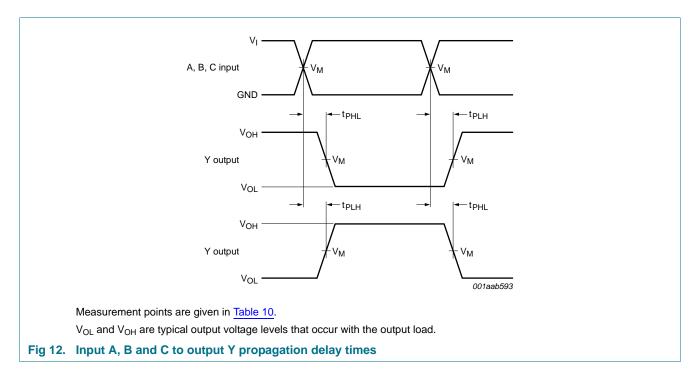


Table 10. Measurement points

Supply voltage	Output	Input		
V _{CC}	V _M	V _M	VI	t _r = t _f
2.3 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 \times V_I$	1.65 V to 3.6 V	≤ 3.0 ns

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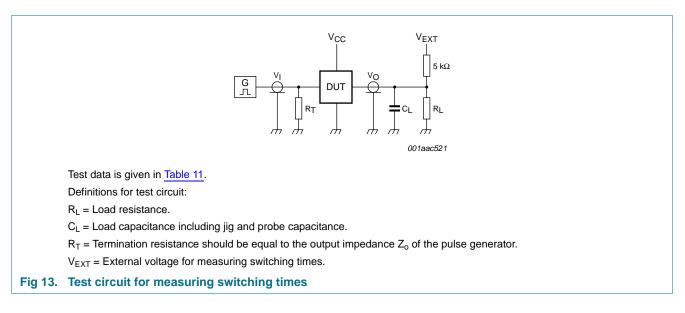


Table 11. Test data

Supply voltage	Load		tage Load V _{EXT}		
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
2.3 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 k\Omega$, for measuring propagation delays, setup and hold times and pulse width $R_L = 1 M\Omega$.

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13. Package outline

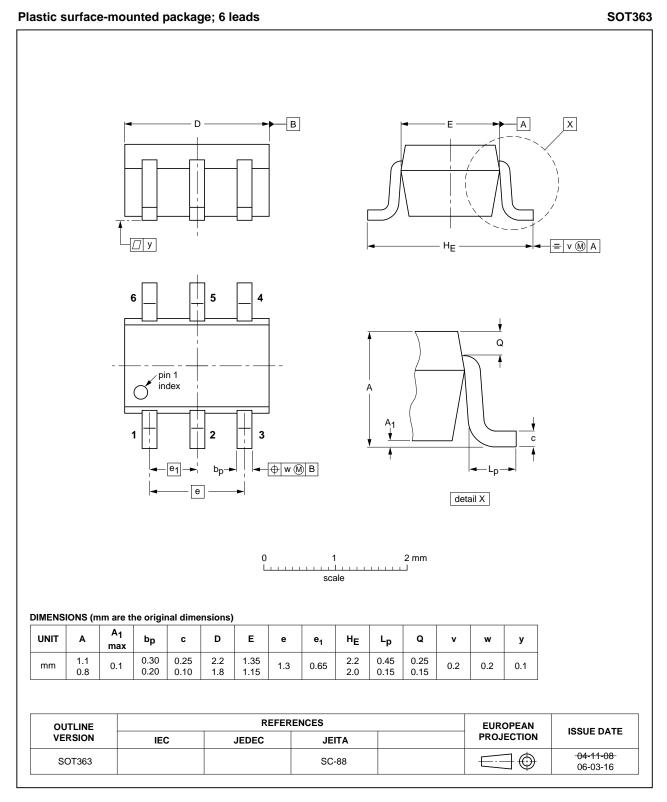


Fig 14. Package outline SOT363 (SC-88)

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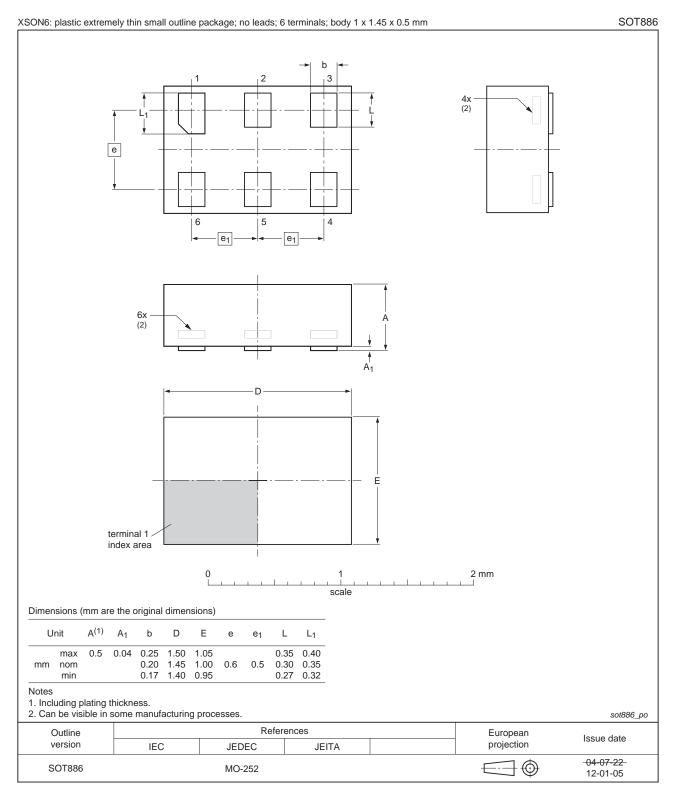


Fig 15. Package outline SOT886 (XSON6)

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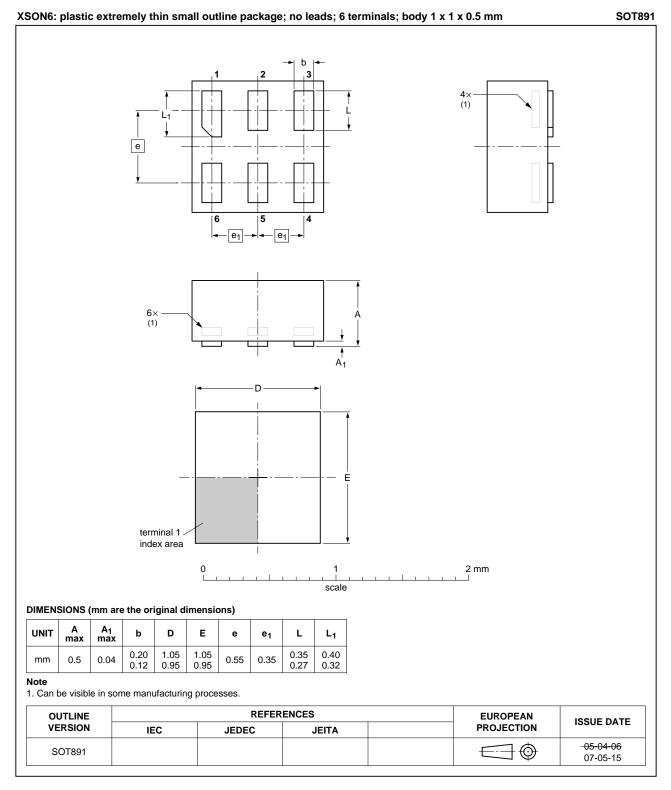
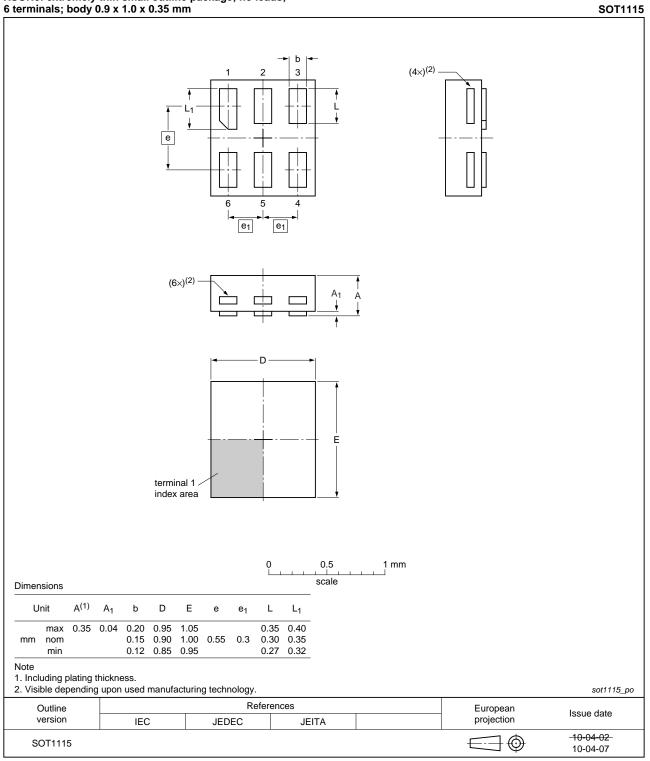


Fig 16. Package outline SOT891 (XSON6)

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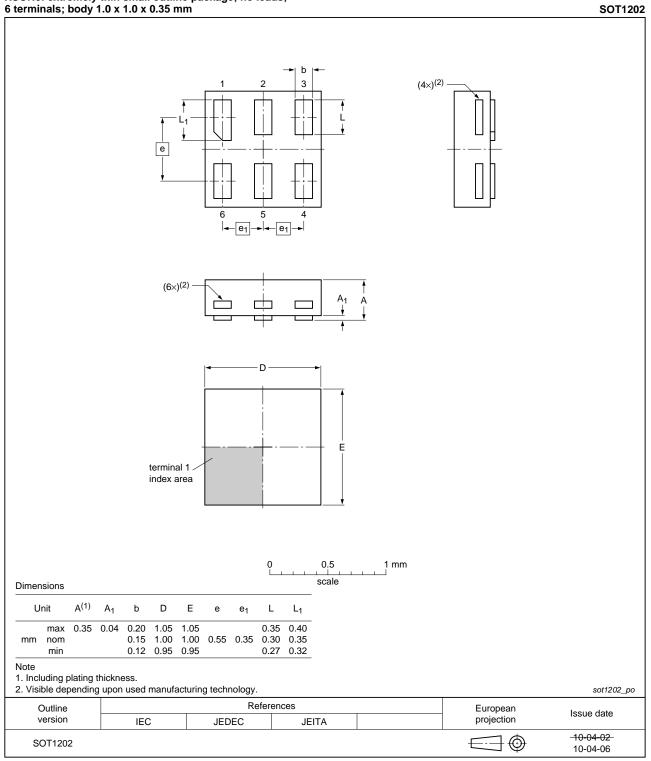


XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

Fig 17. Package outline SOT1115 (XSON6)

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XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 18. Package outline SOT1202 (XSON6)

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14. Abbreviations

Table 12.	Table 12. Abbreviations			
Acronym	Description			
CDM	Charged Device Model			
CMOS	Complementary Metal Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MM	Machine Model			

15. Revision history

Table 13. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1T58 v.5	20120815	Product data sheet	-	74AUP1T58 v.4
Modifications:	 Package out 	tline drawing of SOT886 (<mark>Figur</mark>	e 15) modified.	
74AUP1T58 v.4	20111128	Product data sheet	-	74AUP1T58 v.3
74AUP1T58 v.3	20101018	Product data sheet	-	74AUP1T58 v.2
74AUP1T58 v.2	20090929	Product data sheet	-	74AUP1T58 v.1
74AUP1T58 v.1	20080306	Product data sheet	-	-

16. Legal information

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Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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